## polsid ve cressor

Resin seal-type semiconductor device with improved reliability - has metallic foil wiring lead with lead terminal, semiconductor chip electrically connected to lead terminal and two packages arranged on surface

Patent Assignee: TOSHIBA KK

## **Patent Family**

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JP 6318609	Α	199411		93106865		A	19930507		
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## **Patent Details**

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JP 6318609			$\overline{}$	H01L-021/56	

Abstract: JP 6318609 A

The device comprises a metallic foil wiring lead (6) having a lead terminal (7), a semiconductor chip (3) electrically connected to the lead terminal (7) of the metallic foil wiring lead (6), a first package (21) arranged on the surface of the side where the metallic foil wiring lead (6) is connected to the lead terminal (7) which is connected to the semiconductor chip (3) and formed by pressure-moulding uncured resin to give a seal having an area lower than that of the connection surface side of the semiconductor tip (3), and a second package (22) arranged on the surface of the side where the semiconductor chip (3) is not connected to the lead terminal (7) and formed by pressure-moulding uncured resin to give a seal having an area larger than that of the non-connection surface side of the semiconductor chip (3).

ADVANTAGE - Edge touch between a metallic foil wiring lead and a semiconductor chip does not occur and reliability is improved.

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